




NAINA SEMICONDUCTOR LTD.

(An ISO 9001:2000 Certified Company)

D-95, SECTOR 63, NOIDA (INDIA)

www.nainasemi.com

10 WATT ZENER DIODES

TYPE NO.	NOMINAL ZENER VOLTAGE $V_Z @ I_{ZT}$ Volts	ZENER TEST CURRENT (I_{ZT}) mA	MAX. DYNAMIC IMPEDANCE		MAX. DC ZENER CURRENT (I_{ZM}) @ 75°C Stud Temp. mA	TYPICAL TEMP. COEFF. α_{VZ} %/°C	MAX** REVERSE CURRENT $I_R @ V_R$		POLARITY
			$Z_{ZT} @ I_{ZT}$ OHMS	$Z_{ZK} @ 1mA (I_{ZK})$ OHMS			μA	Volts	
IN2970B	6.8	370	1.2	500	1320	.040	150	5.2	STD. POLARITY ANODE TO STUD  DO4
IN2971B	7.5	355	1.3	250	1180	.045	100	5.7	
IN2972B	8.2	305	1.5	250	1040	.048	50	6.2	
IN2973B	9.1	275	2.0	250	960	.051	25	6.9	
IN2974B	10	250	3	250	860	.055	25	7.6	
IN2975B	11	230	3	250	780	.060	10	8.4	
IN2976B	12	210	3	250	720	.065	10	9.1	
IN2977B	13	190	3	250	660	.065	10	9.9	
IN2978B	14	180	3	250	600	.070	10	10.5	
IN2979B	15	170	3	250	560	.070	10	11.4	
IN2980B	16	155	4	250	530	.070	10	12.2	
IN2981B	17	145	4	250	500	.075	10	13.0	
IN2982B	18	140	4	250	460	.075	10	13.7	
IN2983B	19	130	4	250	440	.075	10	14.0	
IN2984B	20	125	4	250	420	.075	10	15.2	
IN2985B	22	115	5	250	380	.080	10	16.7	
IN2986B	24	105	5	250	350	.080	10	18.2	
IN2987B	25	100	6	250	310	.080	10	18.2	
IN2988B	27	95	7	250	300	.085	10	20.6	
IN2989B	30	85	8	300	280	.085	10	22.8	
IN2990B	33	75	9	300	260	.085	10	25.1	
IN2991B	36	70	10	300	230	.085	10	27.4	
IN2992B	39	65	11	300	210	.090	10	29.7	
IN2993B	43	60	12	400	195	.090	10	32.7	
IN2994B	45	55	13	400	185	.090	10	33.0	
IN2995B	47	55	14	400	175	.090	10	35.8	
IN2996B	50	50	15	500	165	.090	10	36.0	
IN2997B	51	50	15	500	160	.090	10	38.8	
IN2998B	52	50	15	500	160	.090	10	39.0	
IN3099B	56	45	16	500	150	.090	10	42.6	
IN3000B	62	40	17	600	130	.090	10	47.1	
IN3001B	68	37	18	600	120	.090	10	51.7	
IN3002B	75	33	22	600	110	.090	10	56.0	
IN3003B	82	30	25	700	100	.090	10	62.2	
IN3004B	91	28	35	800	85	.090	10	69.2	
IN3005B	100	25	40	900	80	.090	10	76.0	
IN3006B	105	25	45	1000	75	.095	10	76.0	
IN3007B	110	23	55	1100	72	.095	10	83.6	
IN3008B	120	20	75	1200	67	.095	10	91.2	
IN3009B	130	19	100	1300	62	.095	10	98.8	
IN3010B	140	18	125	1400	58	.095	10	100.0	
IN3011B	150	17	175	1500	54	.095	10	114.0	
IN3012B	160	16	200	1600	50	.095	10	121.6	
IN3013B	175	14	250	1750	46	.095	10	135.0	
IN3014B	180	14	260	1850	45	.095	10	136.8	
IN3015B	200	12	300	2000	40	.100	10	152.0	

♦ ELECTRICAL CHARACTERISTICS MEASURED AT 25°C UNLESS OTHERWISE STATED.

♦ TABLE DEMONSTRATES DEVICE CHARACTERISTICS FOR A 10W DEVICE

♦ V_Z MEASURED AT JUNCTION AND CASE TEMPERATURE BOTH AT 25°C.

♦ I_{ZM} IS SELECTED SO THAT A CONSTANT 12.5W POWER DISSIPATION IS OBTAINED (JUNCTION TEMPERATURE RISE 12.75°C).

♦ ZENER IMPEDANCE IS DERIVED FROM 60HZ AC VOLTAGE WHICH RESULTS WHEN AC CURRENT RMS VALUE EQUAL TO 10% OF D.C ZENER CURRENT IS SUPERIMPOSED ON I_Z .

♦ ZENER IMPEDANCE IS MEASURED AT 2 POINTS ON THE REVERSE BREAKDOWN CURVE.

♦ I_{ZM} VALUES DERIVED FOR A $\pm 5\%$ V_Z TOL.

♦ I_{ZM} IS THE VALUE OF ZENER CURRENT AT WHICH POINT 10W POWER DISSIPATION RESULTS.

Standard voltage tolerances are +/- 5% with B suffix, +/-10% with an A suffix, and +/-20% with no suffix